NSN 5961-00-146-9449

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-146-9449 **Inclosure Material:** Metal and ceramic **Overall Length:** 0.710 inches **Overall Diameter:** 0.187 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.187 inches **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 regulator voltage **Voltage Tolerance In Percent:** -5.0 to 5.0 **Current Rating Per Characteristic:** 110.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 10.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 95542-941-032 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 solder stud and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**

No

Fiig:

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Demilitarization: